HF high dynamic "H mode "Mixers

в

Some electronic devices (usable as general purpose switches) can be used for HF up to 30MHz as high dynamic mixer, these are low cost components but it is possible to obtain high dynamic mixers. These components are FETs in quadruple configuration used as switches called 4 Bit Bus Switch, or quadruple logical ports used as switches too. Both are always driven by a C-Mos logical port on low level LO signal. We will not dwell on the explanation of these mixers (see Internet or magazines) the cost of these components is very low because they were developed for consumer market. The trick lies in selecting devices that, among all the many available products, have low parasitic capacity, fast switching times and very low R_{DS} series resistance.

original function		cod.	price €each 1 - 10 pcs
C Mos SMD , 4 bilateral	it is the simpliest and cheapest solution for H mode	CD 4066-SMD	0,50 - 0,45
switch	mixers	CD 4066-DIL	0,80
SMD, 4 bit bus switch	Cin 3pF, 5 dB loss, OL only -10 dBm	FST 3125 M	2,00 - 1,80
DIL , 4 bit bus switch	tr + td(on) = 1 nS fast switching , CDG 0.3 pF , Cout 1.3 pF , +/- 10V , case DIL	SD 5000	7,50
Metallic TO72, single FE	T, it is the single divice contained in the quad SD 5000N	SD 215 DE	see FET
SMD, 4 OR SMD	they are used as rectangular wave form LO, Schmidt	74 HC 86	0,40 - 0,30
SMD, 4 OR SMD	trigger and 180° phase shifter for LO driver	74 AC 86	0,50 - 0,40

wide band, passive BALACED MIXERS **PASSIVE MIXERS** useful informations

The passive mixers are versatile and extraordinary components, they are also suitable for other applications in addition to theirs classic, some of these applications are well known but others a little less. In these few lines we will also give you some little tips on how to best use them.

examples of balanced mixers particular applications							
Balanced Modulator Demodulator DSB	Balanced mixers and modulators are substantially equal, mixers are also used as audio modulators or demodulators provided that the IF port is DC coupled, in fact some years ago they were called also as balaced modulators (see VHF Comm 2-96).						
Phase detector	Applying two identical frequencies are identical to the RF and OL ports, in IF there will be d.c. voltage proportional to the phase difference of the two signals. This is obviously valid only for those mixers who have the IF port coupled in d.c The early 0 synthesizers in the 60s had the phase comparator made by a balaced mixer. Some mixers have a positive polarity output other negative, eg. SBL1 and SRA 1 have negative polarity with offset of 1 mV.						
PSK QPSK Modulator Demodulator	In simple words we can say that two mixers, a 0° hybrid and a 90° hybrid can form a modulator or demodulator for digital signals, this happened for example at the beginning with the first GSM module. In this case, however, the bandwidth is limited to 10-15% of the mixer bandwdth.						
Attenuator and Limiter	By applying a signal to the LO port with RF output port it is possible, through the IF input port, make an attenuation with typical range of 3 - 40 dB. The same function is as limiter, pulse modulator, etc For example, the mixer SRA 1 and SBL 1 have the minimum attenuation at 3 dB with 20 mA of bias.						

For more informations see the manufacturers' catalogues about balanced mixers like, Merrimac, MaCom, Anzac, RHG, MCL, etc... there are often available many application notes of considerable interest.

<u>PASSIVE MIXERS</u>, suggestions on how to use

The RF and IF ports can be freely swapped. For example in the case of conversion up (as in a spectrum analyzer or TX UP converter) RF port is exchanged with the IF as the RF port often has a larger range than IF.

The passive mixers offer very large IMD dynamics, the IF port should be well adapted to broadband for example by a 2 - 4 dB attenuator on IF output to improve the matching (see page 'not connectorized attenuators').

A mixer can be used also beyond its frequency specification, being a broadband aperiodic circuit the slope of degradation is slow. In practical experience degradation is the worsening of insulation between the ports (or of the balance if it is used as a balanced modulator) going up versus frequency the LO port would seem to be more tolerant to overcome its limits either at higher or at lower frequencies.

R.F. elettronica di Rota F. www.rfmicrowave.it info@rfmicrowave.it tel ++39.02.99 48 75 15

fax ++39.02.99 48 92 76

continue, broad band, passive BALANCED MIXERS Pag B 2							
See on the previous page some suggestions on how to use passive mixers							
case	frequency LO and RF	in MHz IF (or RF)	1dB C.P.	LO dBm	1 dB C.P. = Compression Point at -1dB on RF input	cod.	price € each
	0.0005 - 10	· · · · ·	+1	+7	for VLF-LF-MW-HF, LO + RF starting from 500 Hz , hermetic HI-REL case, 50dB insulation	SRA 8	on request
	0.003 - 100	dc - 250	+1	+7	for VLF-LF-MW-HF , HI-REL	GRA 6	
	0.01 - 250	dc - 250	+1	+7	for VLF-LF-MW-HF-VHF, hermetic HI-REL case	TAK 5	on request
big size	0.05 - 200	dc - 200	+1	+7	TAK 5 pin compatible, hermetic HI-REL case	TAK 5R	special offer 19,50
metallic	0.02 - 200	dc - 200	+1	+7	replaceale and pin compatible with TAK5R	SBL 3	see TAK5
case	0.05 - 200	dc - 200	+1	+7	Watkins-Johnson, 50 dB high insulation up to 30 MHz, 35 dB up to 200 MHz	M6D 50	18,50
	0.5 - 500	dc - 500	+1	+7	HI-REL ceramic case	GRA 1	16,00
	0.5 - 500	dc - 500	+1	+7	HI-REL version of SBL 1	EMA 1S	11,50
	1 - 500	dc - 500	+1	+7	hermetic case, replaceale and pin compatible with SBL 1 - IE 500 , or in plastic version ASK1	HPF 505	10,50
2 1	1 - 500	dc - 500	+1	+7	same of HPF 505 and SBL 1	IE 500	see HPF500 or SBL1
[⊡]	1 - 500	dc - 500	+1	+7	see also HPF505 100% compatible	SBL 1	11,60
20	1 000	40 000		.,	replaceale and pin compatible with HPF 505X	SBL 1X	see HPF505>
••]⊥ ⊢10⊣	10 - 1000	5 - 500 (dc-1000)	+1	+7	replaceale and pin compatible with SBL1X	HPF 505X	special offer 9,00 3pcs=8,00 ea.
\bigtriangleup	1 - 1500	dc - 1000	+10	+17	HIGH DYNAMIC pin compatible with SRA 1H	EMA 220 X	special offer 25,00
(Jac	0.5 - 500	dc - 500	>+8	+17	HI-REL version -54 / +100°C, high insulation typical 50 dB in HF and high dynamic IP +25dBm level of desensitization at -1dB = +17dBm	M9BC Watkins Johnson	33,00
2 1 ••	0.5 - 500	dc - 500	+10	+17	<u>HIGH DYNAMIC</u> , hermetic HI-REL case, see also EMA220X - TFM 3MH or SMD cheaper version RMS 1H	SRA 1H	not available
• a 6 • pin	10 - 3000	10 - 1000	+10	+17	HIGH DYNAMIC hermetic HI-REL case	SRA 11H	on request
···	1 - 750	dc - 750	+10	+17	HIGH DYNAMIC	SRA 1 WH	33,00
6 5 GRA M9BC	5 - 1200	dc - 1200	+10	+17	HIGH DYNAMIC hermetic HI-REL case, typical insulation 30-35 dB low loss typical 5.4-6 dB (list price MCL 36 €)	SRA 173H	special offer 29,00
25 x 12.7 mm	0.07 - 200	dc - 200	+15	+23	VERY HIGH DYNAMIC , hermetic HI-REL case	RAY 3	55,00
	1 - 500	dc - 500	+15	+23	<u>VERY HIGH DYNAMIC</u> ≅ RAY 1	MD 138	59,00
	100 - 2500	dc - 500	+15	+23	VERY HIGH DYNAMIC	RAY 11	88,00
	0.1 - 500	0.01 - 500	+20	+23	<u>VERY HIGH DYNAMIC</u> , hermetic HI- REL case, 40 dB insulation	SAY 1	66,00
					Vari-L	CM-2	on request

HPF 505 lab tests : P1dB = +2 dBm (input power) , IMD not very sensible at LO level (within +/- 3 dB)

continue, broad band, passive BALANCED MIXERS Pag B 3							
See on the previous page some suggestions on how to use passive mixers							
case		cy in MHz	1dB C.P.		1 dB C.P. = Compression Point at -1dB on RF input	cod.	price €each
small size	1 - 250	dc - 250	+9	+13	high dynamic and excellent cheaper alternative to the type SRA1H, see note below	EMT 3 MH TFM 3 MH	special offe 20,00
metallic	0.04 - 400	dc - 400	+1	+7	from VLF to UHF, positive polarity phase detector	TFM 3	24,00
	2 - 600	dc - 600	+1	+7	-	TUF 1	12,00
solo 4 PIN	1 - 1000	dc - 1000	+1	+7		TFM 2 = EMT 2	19,00
	5 - 1250	dc - 1250	+1	+7		EMT 4 = TFM 4	special offer 19,50
_ ⊢12.5⊣ 5.5 1 · · · · I	5 - 1500	dc - 1000	+1	+7		EMT 5 = TFM5	special offer 19,00
	20 - 1500	dc - 1000	+1	+7	IP3 +13 dBm	CLP 311	special offer 18,00
5.5 :··:	0.1 - 500	dc - 500	+1	+7	hermetic HI-REL 8 pins, case height: 10 mm	SAM 3	19,00
TFM 15-9 a 6 pin	10 - 3000	10 - 800	+5	+10	it is a variant of TFM15 with 6 pins instead of 4 pins, 2 pins further enhance the connection of GND, the case is 10 mm high	TFM 15-9	special offe 36,00
	50 - 1000	dc - 1000	+9	+13	high dynamic	ETUF-2MH (sm) (= TUF-2MH)	11,00
a 8 pin _⊢12.5⊣	5 - 1000	dc - 1000	+14	+17	high dynamic 4 dB more than SRA 1H	TFM 2H	38,00
5.5	0.1 - 250	dc - 250	+14	+17	high dynamic 4 dB more than SRA 1H	TFM 3H	26,00
	50 - 1000	dc - 1000	+14	+17	it can be replaced with TFM 2H	TUF 2H	see TFM2H
HIGH DYNAMIChigh and medium dynamic miniature TFM series mixers at the same LO level, they have a higher dynamic than the SRA SBL models about +3 / +4 dB, see examples TFM 3MH and TFM 2H: - TFM 2H and TFM 3H with the same LO level of SRA 1H, they have a dynamic of 4 dB more - TFM 3MH with a LO level of 4dB less than SRA 1H type it has only 1dB less in dynamic and compression (it is usable alse at 430 MHz with +1 dB loss).							
passive					llic case	1	
Case size 13x10x3		uency in Mi IF Id RF (or F	. (LO JBm 1 dB C.P. = Compression Point at -1dB on RF input	cod.	price €each
flat metalli	c 10 - 1	· · · · ·		+1	+7 more tolerant versus LO level	MD 113	on reques
case gold plate	d 10 - 1	1500 dc - 1	500	+1	+7 more tolerant versus LO level	MD 149 (= LMX149)	40,00
- мр Қ ՀՀ Հ	800 -	3000 dc - 1	500	+1	+7 Watkins - Johnson , often usen in spectrum analyzers	M4G (= LMX156)	43,00
M4G 📙 📙 H MA4 🎽 👖	IF RF ■ 10 - 10	1500 dc - 1	000	+1	+7 Watkins - Johnson HI-REL QPL	MA4-100	40,00

continue	, broad 1	band, p	ass	ive	BALANCED MIXERS	8	Pag B 4
case	frequency LO and RF	in MHz IF (or RF)	1dB c.p.		1 dB C.P. = Compression Point at -1dB	Cod.	price € each
SMD	1 - 1000	dc - 1000	+1	+7		ADE 2ASK	9,50
	1600 - 3500	dc - 1500	+1	+7		ADE 35	off 12,00
or	1 - 600	dc - 600	+1	+7	miniature, specifications as SBL1	ASK 1	7,00 - 6,40
Plastic	2 - 500	dc - 500	+1	+7		JMS 1	7,00
Ť	0.5 - 500	dc - 500	+1	+7	they are exactly the same	RMS 1 EMRS 1	9,00 6,50 - 5,90
ADE 📭	5 - 1000	dc - 1000	+1	+7	SMD, see MD4007X cheaper	RMS 2	on request
JMSRMS	5 - 1500	dc - 1000	+1	+7	they are exactly the same	EMRS 5	9,00 3pcs = 8,00 ea.
-					special offer	RMS 5	10pcs = 7,00 ea.
SYM	5 - 1900	5 - 1000	+1	+7		RMS 11 X	5,50 - 4,85
	1 - 1000	dc - 1000	+1	+7	100% = RMS 2	MD 4007X	special offer 5,90
	200 - 3000	dc - 1000	+1	+7		RMS 30 (= EMRS 30)	special offer 9,50 3 pcs = 8,50 ea. 10 pcs = 7,50 ea.
	2400-6700	dc - 1000	+1	+7	good insulation L-R typ. >32 dB L-I typical >23 dB	MBA 671	12,00
₩₩₩₽ └_J	2 - 500	dc - 500	+5	+10	very good insulation	RMS 1LH	9,50
	5 - 2500	5 - 1500	+9	+13	very wide bandwidth , very good insulation LO-RF and LO-IF typical 30 dB Mil M-28837 -55 / +100°C	EMRS 25 MH (= RMS 25MH)	special offer 9,50 3 pcs = 8,50 ea. 10 pcs = 7,50 ea.
	2 - 500	dc - 500	+11	+17	HIGH DYNAMIC	RMS 1H	12,00
	50 - 2000	50 - 2000	+10	+17		SYM-11H	19,00
LO = 200 – 130 RF or IF = 300 - RF or IF = dc –	- 1000		+1	+7	special offer	RMS 45	6,00 3 pcs = 5,00 ea.

PAM 42: a very particular mixer

This passive double-balanced mixer is very special since it was especially made for UP converters, a so strange frequency range makes it useful for building spectrum analyzers or tracking generators. The case is professional gold plated and it is very particular but well-suited for RF assemblies.



other parts available from us are also listed, as an example, in the scheme up here

SIM series, a new family of microwave mixer

This is a new family of double balanced passive mixers from Minicircuits with a wide bandwidth , both in RF-OL (up to 15 GHz) and in IF (up to 4 GHz) .

They are fabricated using the LTCC technology , Low Temperature Co-fired Ceramic , with multilayer circuits , using multiple layers of ceramic substrate tape . The benefits of LTCC are :

- Super small size , this is very important for the microwave technology .

- High repeatability and high performances using low loss ceramic substrate .

- Low cost for high volume production .

LTCC is a repeatable process, it can reliably produce large quantities of microwave components, measuring a fraction of the size of components fabricated with conventional substrate materials.

Thanks to wide IF bandwidth they are usable as up and down converter , covering a large number of applications to 15 GHz . With 8 different models , the frequency range is from 750 MHz to 15 GHz and OL level from +4 to +10 dBm .

High isolation typical 25 dB (20 to 35 dB) , not so bad for very wide bandwidth devices .

Minicircuits 3.700 - 10.000 dc - 4.000 +1 +13 +7 SIM-14 16,80 750 - 4.200 dc - 1.500 +1 +12 +7 SIM-43 14,90 2.300 - 8.000 dc - 3.000 +1 +15 +7 SIM-83 14,40 3.400 - 15.000 dc - 4.000 +1 +10 +7 SIM-153 19,60 750 - 6.000 dc - 1.500 +3 +12 +10 SIM-63LH 16,80 1.700 - 8.000 dc - 3.000 +3 +18 +10 SIM-83LH 14,40	case SMD 5 x 4.5 mm	Frequency i LO - RF	n MHz IF (or RF)	1dB c.p. dBm	IP3 dBm	OL dBm	Cod.	price € each
Shin 750 - 4.200 dc - 1.500 +1 +12 +7 SIM-43 14,90 2.300 - 8.000 dc - 3.000 +1 +15 +7 SIM-83 14,40 3.400 - 15.000 dc - 4.000 +1 +10 +7 SIM-153 19,60 750 - 6.000 dc - 1.500 +3 +12 +10 SIM-63LH 16,80 1.700 - 8.000 dc - 3.000 +3 +18 +10 SIM-83LH 14,40		2.400 - 7.000	dc - 3.000	+1	+12	+4	SIM-73L	17,90
SIM 750 - 4.200 dc - 1.500 +1 +12 +7 SIM-43 14,90 2.300 - 8.000 dc - 3.000 +1 +15 +7 SIM-83 14,40 3.400 - 15.000 dc - 4.000 +1 +10 +7 SIM-153 19,60 750 - 6.000 dc - 1.500 +3 +12 +10 SIM-63LH 16,80 1.700 - 8.000 dc - 3.000 +3 +18 +10 SIM-83LH 14,40	Minicircuits	3.700 - 10.000	dc - 4.000	+1	+13	+7	SIM-14	16,80
Shi 3.400 - 15.000 dc - 4.000 +1 +10 +7 SIM-153 19,60 750 - 6.000 dc - 1.500 +3 +12 +10 SIM-63LH 16,80 1.700 - 8.000 dc - 3.000 +3 +18 +10 SIM-83LH 14,40		750 - 4.200	dc - 1.500	+1	+12	+7	SIM-43	14,90
3.400 - 15.000 dc - 4.000 +1 +10 +7 SIM-155 19,00 750 - 6.000 dc - 1.500 +3 +12 +10 SIM-63LH 16,80 1.700 - 8.000 dc - 3.000 +3 +18 +10 SIM-83LH 14,40		2.300 - 8.000	dc - 3.000	+1	+15	+7	SIM-83	14,40
1.700 - 8.000 dc - 3.000 +3 +18 +10 SIM-83LH 14,40	- SIM	3.400 - 15.000	dc - 4.000	+1	+10	+7	SIM-153	19,60
		750 - 6.000	dc - 1.500	+3	+12	+10	SIM-63LH	16,80
3.200 - 15.000 dc - 4.000 +3 +18 +10 SIM-153LH 19,60		1.700 - 8.000	dc - 3.000	+3	+18	+10	SIM-83LH	14,40
		3.200 - 15.000	dc - 4.000	+3	+18	+10	SIM-153LH	19,60

Hittite ceramic case C8	HMC141	6.000 - 15.000	dc - 2.000	+10	+20	+15	HMC 142 C8	on request
----------------------------------	--------	----------------	------------	-----	-----	-----	------------	---------------

continue, MIXERS

continue , MIXERS

pag B7

Mixer + Front-end 21 - 24 GHz



This is a 21 to 24 GHz receiving FRONT-END, the RF input is in WR42 waveguide with its input matching, it follows the first isolator in order to match the waveguide and the amplifier. The low noise amplifier is a GaAsFET internal matched MMIC already matched by the manufacturer on the lower 21-22GHz band, type FMC2122LN-03, or on the higher 22-23 GHz band, type FMC2223LN-03. The characteristic of this amplifier is a gain of 12-13 dB with a noise figure of 3-3.5 dB and an excellent stability and repeatability very hard to obtain at these frequencies. There is another insulator as matching to avoid the return of the LO signal towards the antenna. The mixer consists of 2 quads of Schottky beam lead HP HSCH 9301. This configuration, well known in microwave field, allows to use a LO at half frequency of the normally required simplifying the LO circuit. Here follows a wide band hybrid for the IF output centered at 1GHz but usable from 500 MHz to 1500 MHz.

	low band model	high band model			
	RF-22WR42	RF-23WR42			
	21 - 22,7 GHz max 20.6 - 23 GHz	22,4 - 23,8 GHz max 22,2 - 24 GHz			
frequency	(freq RF - freq IF): 2 (about 10-11 GHz)	(freq RF + freq IF): 2 (about 11,8-12,6 GHz)			
level	from +12 to +13 dBm				
	±1 GHz max 400 - 1500 MHz				
	3 - 6 dB				
	4.5 - 6 dB				
n	about 15 dB , depending on IF and LO frequency				
ırn loss	about -15 dB				
	LO and IF with SMA f RF input with WR42 waveguide				
	+8V 50mA -5V 10 mA				
	height: 26mm width	: 60mm length: 91 mm			
	frequency level	RF-22WR42 21 - 22,7 GHz max 20.6 - 23 GHz frequency (freq RF - freq IF): 2 (about 10-11 GHz) level from +12 ±1 GHz max 3 - 4.5 n about 15 dB, dependir irn loss about LO and IF with SMA f F +8V 50mA			



Type or family	description		cod.	price € each 1 - 10 pcs
Analog Devices Analog AD 831	high dynamic + 24 dBm IP3 e +10 dBm 1dB C.P., few mixers with dynamic (similar to a passive type LO level only -10 dBm, it is used also as direct co- base band, image rejection mixer and modulator o I/Q complete with IF high dynamic post-amplifier a need complicate diplexers with output terminations	+13/+17dBm), nversion of or demodulator and it doesn't	AD 831 AP	17,70
in - out IF - RF in - out RF - IF	up - down converter ultralinear it is usabe both as up and down high dynamic c IP3 up to + 26dBm, SMD MW-6 case LO + RF 500 - 2.500 MHz IF 10 - 2.500 MH	mixer onverter	CMY 210	7,80
QPSK I & Q modulator	I/Q modulator, RF out 25 - 250 MHz it is used in transmission combined with an UP converter (ex 2006) it becomes a complete transmitter. Band I & Q > 40 MHz, LO level -12 dBm, RF o	xample HPMX	HPMX 2005	8,50
2 GHz UP converter filtro esterno	IF input dc - 1 GHz RF output 800 - 2500 MH GHz) it is an up converter for example it can be 2GHz transmitter with modulation on IF port or a analyzers with dc-1GHz RF input and first IF > 1 internal power amplifier up to +2 / +9 dBm, as Lu -3dBm because it has a LO internal amplifier.	HPMX 2006	1 - 4 pcs 3,9 5 - 9 pcs 3,5 10-30 pcs 3,2 31-99 pcs 2,9	
Ð	RF port up to 5 GHz, IF port up to 1 GHz , IF an are amplified so -5dBm of LO are enough , it is a 50-3000 MHz with 8 dBG , it is usable from 5 to with 0 dBG at 6 GHz	optimized at	IAM 81008	special offe 1 - 4 pcs 3,3 5 - 9 pcs 2,9 10-30 pcs 2,6 31-99 pcs 2,3
i)	as above but with HI-REL golden glass case -5	5 / + 125°C	IAM 81018	19,50
ENA external filter	it is a complete RX front-end from 100 MHz to 2 low noise , Vc = 3 V / 16 mA RF + LO : 100 MHz - 2.5 GHz LO 0 dBm LNA : 14 dBG @ 100 MHz - 8dBG @ 2.5 GHz IF : dc - 500 MHz, 16 pins SMD case	2.5 GHz	LMX 2216 M	special offe 1 - 4 pcs 3,3 5 - 9 pcs 2,9 10-30 pcs 2,6 31-99 pcs 2,3
DIL metallico	LO + RF + IF dc - 80 MHz , typical modulator and demodulator for SSB and CW receivers, it	metallic case	MC 1496 MET	2,90
George C	is also a frequency doubler etc	DIL case	MC 1496 DIL	2,60
Ð	it is very wide band mixer both as Down and Up RF input dc - 2.000 MHz IF and LO output 10 - 2.000 MHz LO with internal driver it needs only 0dBm , gain		PMB 2330 T	1 - 9 pcs 2,9 10 + pcs 2,4

continue, ACTIVE MIXERS

Type or family	description	cod.	price € each 1 - 10 pcs
RF2411 LNA LNA LNA	it is a HBT high-performance technology I.C. that form a complete low-noise front-end for receiving from 400 to 2000 MHz, it is also usable from 10 to 2,500 MHz, 3 to 6V power supply, 14-pins SMD case 1.6 dBNF @ 800 MHz - 2.6 dBNF @ 1800 MHz 10-14 dBG , due to the fact that it is not connected to the second stage it is possible to insert an RF filter between the 2 LNA stages, reverse insulation > 25 dB 2 nd stage LNA 12-16 dBG	special offer 1 - 9 pcs 5,50 10 + pcs 4,70	
	MixerLO = 0 dBm, LO-RF + LO-IF insulation typ. > 25dBIFdc - 150 MHz , max 200 MHz	RF Micro List Price 9,6 \$	
	it is a high performances front-end for RX from 400 to 1300 MHz with low noise first stage, in fact the total noise figure (fist stage + mixer) is about 2,7 dBNF that is equal to about -120/-118dBm of sesibility at 12 dBs/N, it has a good thermal compensation within +/-0.2dBG from -40 to +85°C LNA first stage : 1.6dBNF @ 900 MHz 12dBG 1.6dBNF @ 430 MHz 15dBG mixer : 5 - 9 dBG LO only -7dBm because it is with internal buffer, LNA stage and mixer are not connected so it is possible to add an external filter, SMD case. Many application notes are available, see AN1777+1000+95021	SA 601 DK	3,90
602 e 612	RF port up to 500 MHz , LO port up to 200 MHz , double-balanced mixer with 15dBg in HF and 10dBg in VHF .	SA 602 AN	1 - 9 pcs 2,80 10 + pcs 2,50
	NE 602 and 612 are obsolete and out of production, they can be replaced by SA602. NE= old versions 0°C/+70°C SA= new versions -40°C/+125°C	SA 602 AD	3,00
DIL	it is a double-balanced mixer up to 75 MHz for HF receivers or it can be used as balanced modulator for SSB transmitters, -30 / +85 ° C	SL 1641 C	7,80
	it is usable up to 200 MHz for HF and VHF, with external or internal self-oscillating LO, IF can be typically 10.7 MHz or 455 KHz, it is used also as limiter stage up to 50 MHz	SO 42 P	3,00
	It is a general purpose mixer with RF an LO up to 200MHz, IF up to 30 MHz, it has an AGC out to drive some PIN diodes, internal LO	TDA 1062	2,00
	it is a complete front end from 500 to 2400 MHz with many functions: 1.3 - 2,7 GHz internal OL, IF amplifier with AGC, internal prescaler to drive a sinthesizer, etc it was born as TV sat receiver, ultra-miniature SMD case	TDA 8010 M	1 - 9 pcs 3,00 10 + pcs 2,60